

## INCHANGE SEMICONDUCTOR

## isc N-Channel MOSFET Transistor

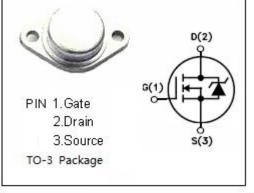
## 45N05

### • FEATURES

- Drain Current  $I_D$ = 45A@ T<sub>C</sub>=25°C
- Drain Source Voltage-
  - : V<sub>DSS</sub>= 50V(Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 0.04 Ω (Max)
- Fast Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

Switching power supplies, converters, AC and DC motor controls

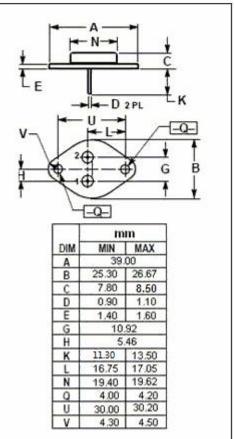


## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	50	V	
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V	
ID	Drain Current-Continuous	45	А	
I <sub>DM</sub>	Drain Current-Single Plused	100	А	
PD	Total Dissipation @T <sub>c</sub> =25℃ 150		W	
Tj	Max. Operating Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	°C	

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.63	°C/W	
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	62.5	°C/W	





# isc N-Channel MOSFET Transistor

## 45N05

## • ELECTRICAL CHARACTERISTICS

T <sub>c</sub> =25℃ unless otherwise speci	fied
--	------

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =1mA	50			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =1mA	2.0		4.0	V
V <sub>SD</sub>	Diode Forward On-voltage	I <sub>S</sub> = 22.5A ;V <sub>GS</sub> = 0			1.4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 22.5A			0.04	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0			±100	nA
ldss	Zero Gate Voltage Drain Current	V <sub>DS</sub> =40V; V <sub>GS</sub> = 0			1	μA
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =25V;			3000	
C <sub>rss</sub>	Reverse Transfer capacitance	V <sub>GS</sub> =0V;			750	pF
Coss	Output Capacitance	f⊤=1MHz			1800	

### **NOTICE:**

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.